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(54) **METHOD AND APPARATUS FOR WAFER-LEVEL TESTING OF SEMICONDUCTOR LASER**

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(58) **Field of Search** **356/432-440, 356/237.1-237.5; 324/767, 760, 765; 372/43, 45, 50, 46**

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(57) **ABSTRACT**

A system and method for manufacturing and wafer-level testing properties of a wafer comprises a chuck receiving a wafer to be tested and a pump light source directing an output beam toward selected locations on a wafer received on the chuck in combination with a laser light detector detecting light emitted from the wafer and a pump beam aiming mechanism selectively varying a position at which the pump light source output beam enters the wafer.

31 Claims, 3 Drawing Sheets

